

Raytheon

**Decompensated Wide-Bandwidth
Dual Operational Amplifier**

RC4562

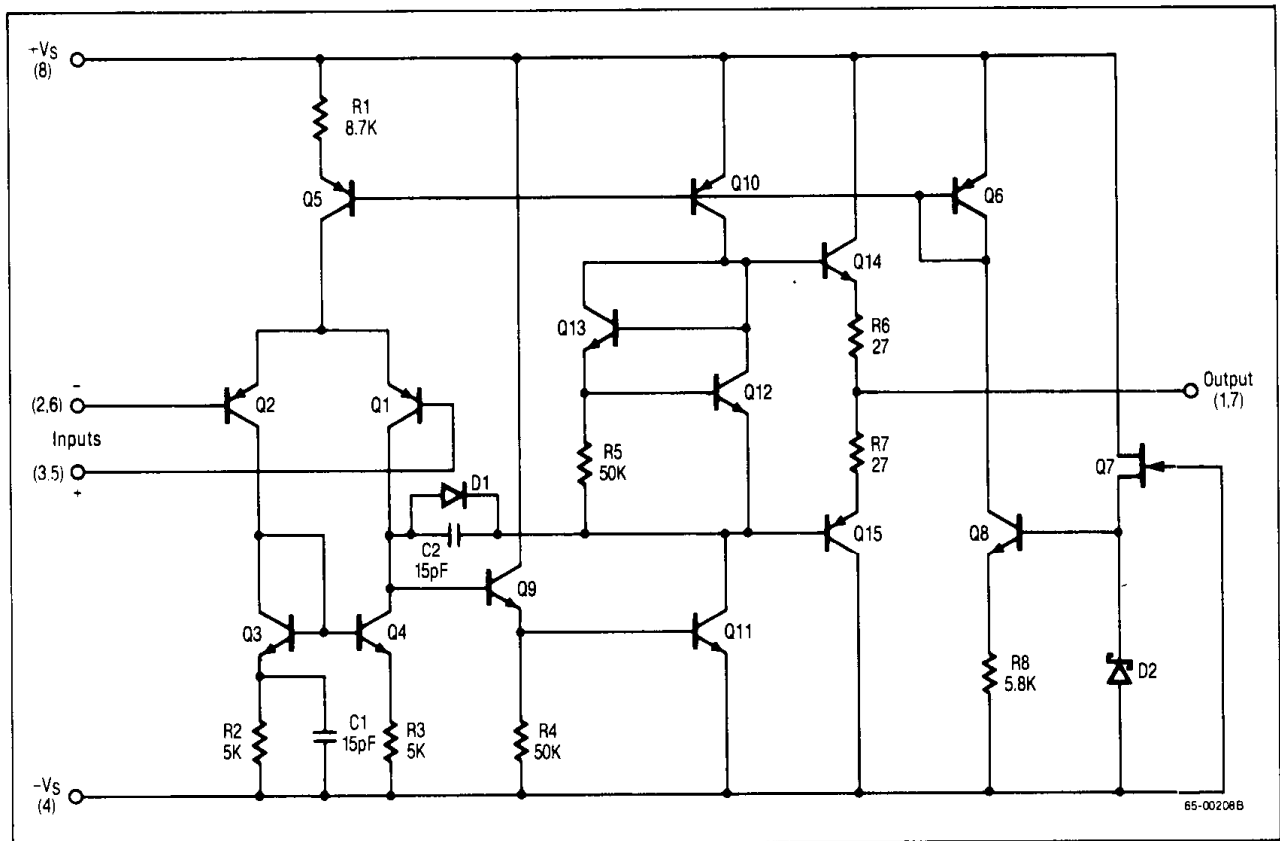
Features

- Frequency compensated for gains >10
- Unity gain bandwidth — 15MHz
- Slew rate — 7.0V/μS
- Noise voltage at 1kHz — 5.5nV/√Hz
- Noise current at 1kHz — 0.2pA/√Hz
- ±10V Output into 600Ω loads
- 0.005% distortion at 9.0V_{RMS}
- Supply current per amplifier — 1.8mA
- Output short circuit protected

Description

The 4562 integrated circuit is a high gain, wide-bandwidth, low noise, dual operational amplifier capable of driving 20V peak-to-peak into 600Ω loads. The 4562 is frequency compensated for closed loop gains greater than 10. The 4562 combines many of the features of the popular 4558 as well as providing the capability of wider bandwidth, and higher slew rate and less noise make the 4562 ideal for audio preamplifiers, active filters, telecommunications, and many instrumentation applications. The availability of the 4562 in the surface mounted micro-package allows the 4562 to be used in critical applications requiring very high packing densities.

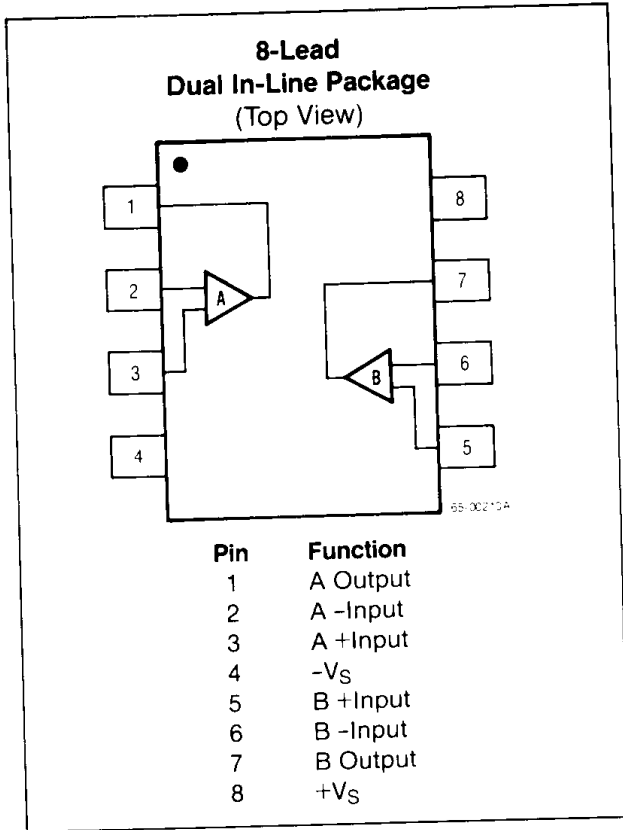
Schematic Diagram (1/2 Shown)



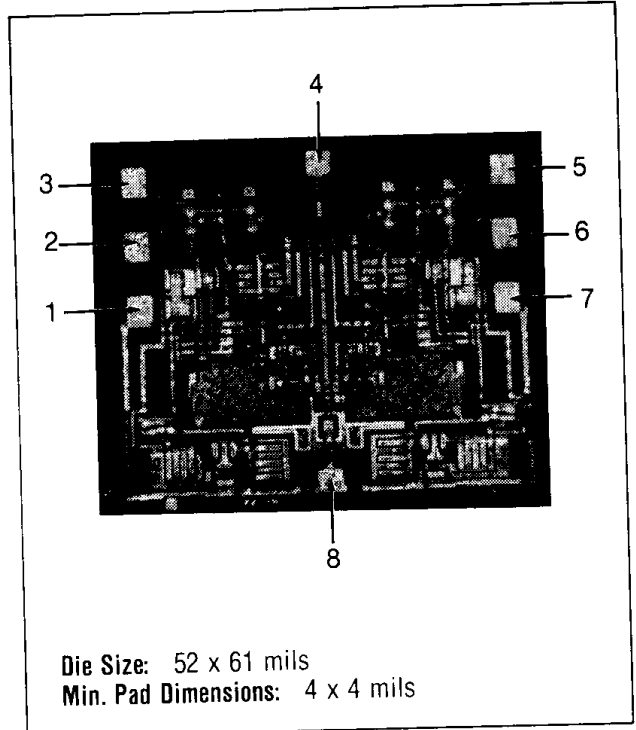
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Decompensated Wide-Bandwidth Dual Operational Amplifier

Connection Information



Mask Pattern



Thermal Characteristics

	8-Lead Micro-Pak Plastic DIP	8-Lead Plastic DIP
Max. Junction Temp.	125°C	125°C
Max. P _D T _A < 50°C	300mW	468mW
Therm. Res. θ_{JC}	—	—
Therm. Res. θ_{JA}	240°C/W	160°C/W
For T _A > 50°C Derate at	4.17mW per °C	6.25mW per °C

Absolute Maximum Ratings

Supply Voltage	±18V
Input Voltage ¹	±15V
Differential Input Voltage	30V
Output Short Circuit Duration ²	Indefinite
Operating Temperature Range	-20°C to +75°C
Lead Soldering Temperature (10 Sec)	
RC4562NB	+300°C
RC4562M	+260°C

Notes: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

2. Short circuit may be to ground on one amp only. Rating applies to +75°C ambient temperature.

Matching Characteristics

(V_S = ±15V, T_A = +25°C)

Parameter	Conditions	Typ	Units
Voltage Gain	R _L ≥ 2kΩ	±1.0	dB
Input Bias Current		±15	nA
Input Offset Current		±7.5	nA
Input Offset Voltage	R _S ≥ 10kΩ	±0.2	mV

Ordering Information

Part Number	Package	Operating Temperature Range
RC4562M	Micro-Plastic	-20°C to +75°C
RC4562NB	Plastic	-20°C to +75°C

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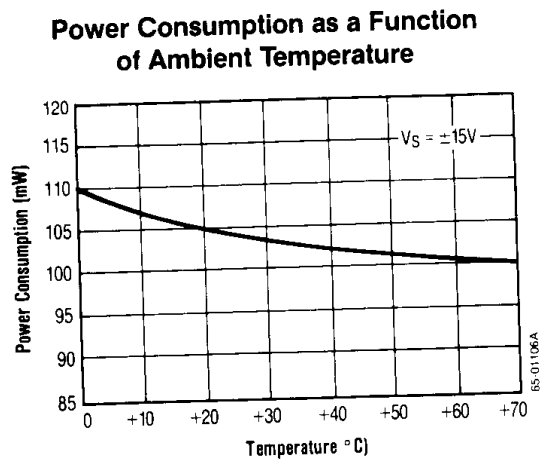
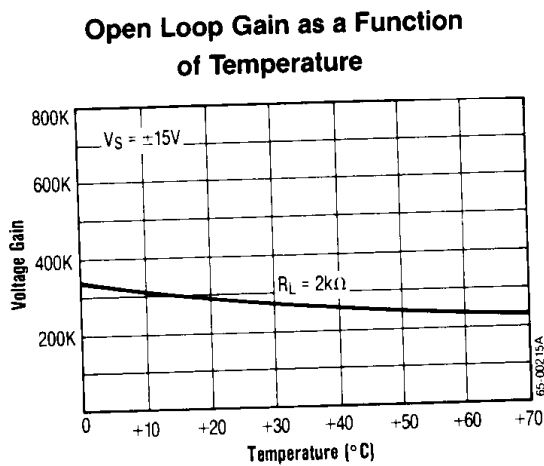
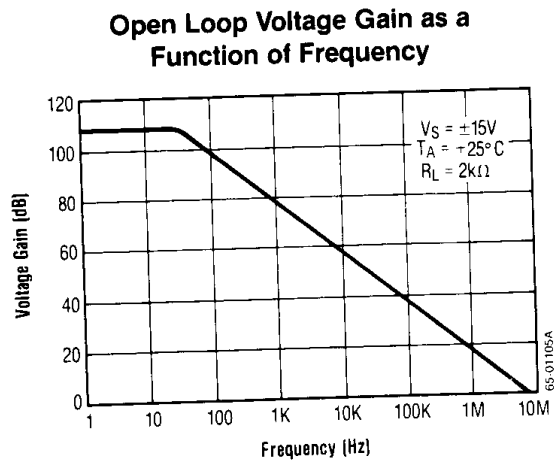
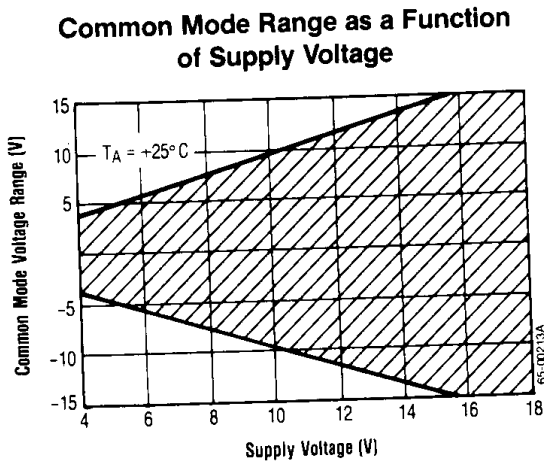
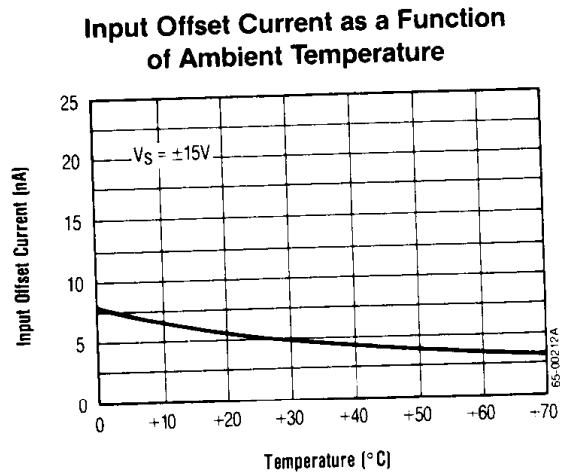
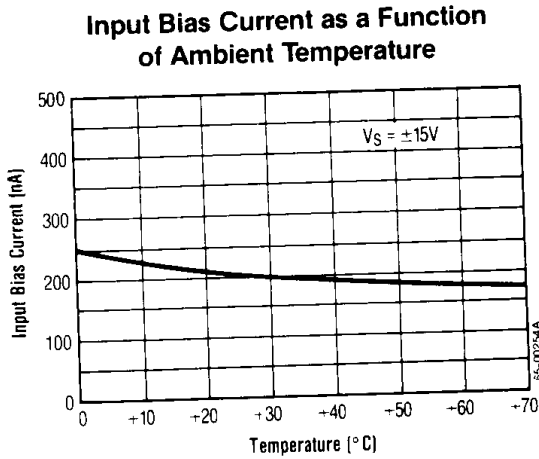
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Electrical Characteristics ($V_S = \pm 15V$ and $T_A = +25^\circ C$ unless otherwise specified)

Parameters	Test Conditions	Min	Typ	Max	Units
Input Offset Voltage	$R_S \leq 10k\Omega$		1.0	6.0	mV
Input Offset Current			5.0	200	nA
Input Bias Current			200	500	nA
Input Resistance		0.3	1.0		$M\Omega$
Large Signal Voltage Gain	$R_L \geq 2k\Omega$, $V_{OUT} = \pm 10V$	20	300		V/mV
Output Voltage Swing	$R_L \geq 10k\Omega$	± 12	± 14		V
	$R_L \geq 2k\Omega$	± 10	± 13		
Input Voltage Range		± 12	± 14		V
Common Mode Rejection Ratio	$R_S \leq 10k\Omega$	70	90		dB
Power Supply Rejection Ratio	$R_S \leq 10k\Omega$	76	90		dB
Power Consumption (All Amplifiers)	$R_L = \infty$		100	170	mW
Transient Response	$V_{IN} = 20mV$, $R_L = 2k\Omega$		0.06		μS
Overshoot	$C_L \leq 100pF$, Gain = 10		60		%
Slew Rate	$R_L \leq 2k\Omega$, Gain = 10		7.0		$V/\mu S$
Channel Separation	$f = 10kHz$ $R_S = 1k\Omega$, Gain = 100		90		dB
Unity Gain Bandwidth	Gain = 10	8.5	15		MHz
The following specifications apply for $-20^\circ C \leq T_A \leq +75^\circ C$					
Input Offset Voltage	$R_S \leq 10k\Omega$			7.5	mV
Input Offset Current				300	nA
Input Bias Current				800	nA
Large Signal Voltage Gain	$R_L \geq 2k\Omega$, $V_{OUT} = \pm 10V$	15			V/mV
Output Voltage Swing	$R_L \geq 2k\Omega$	± 10			V
Power Consumption	$T_A = +75^\circ C$		90	150	mW
	$T_A = -20^\circ C$		120	200	

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Typical Performance Characteristics

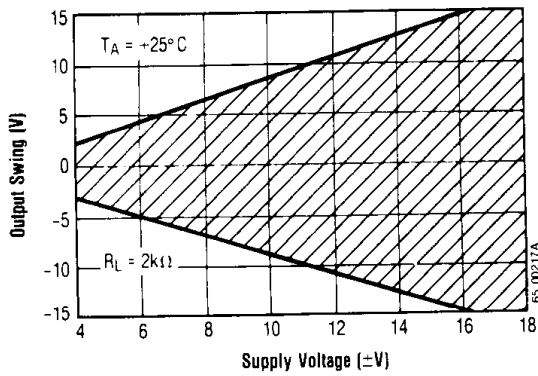


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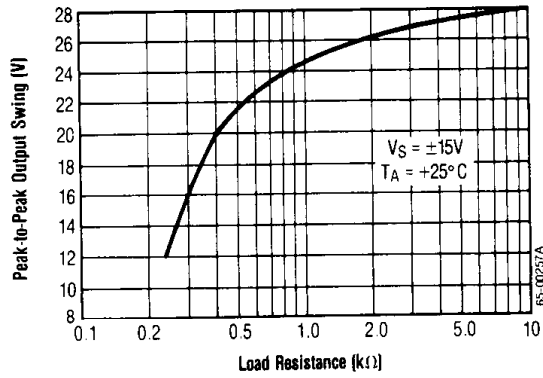
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Typical Performance Characteristics (Continued)

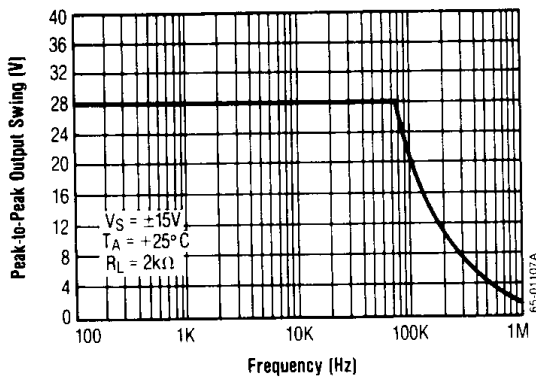
Typical Output Voltage as a Function of Supply Voltage



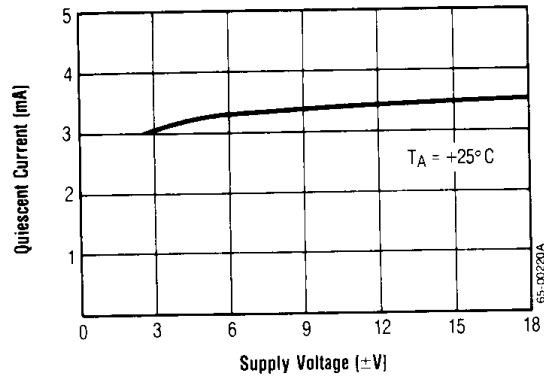
Output Voltage Swing as a Function of Load Resistance



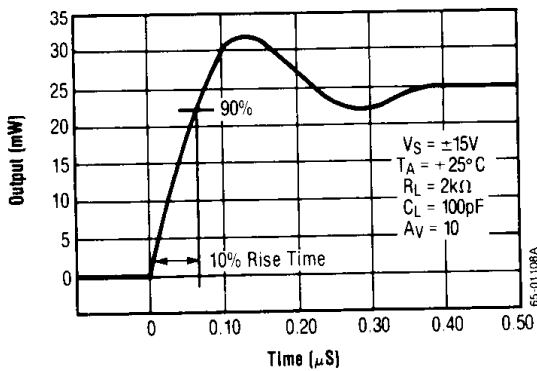
Output Voltage Swing as a Function of Frequency



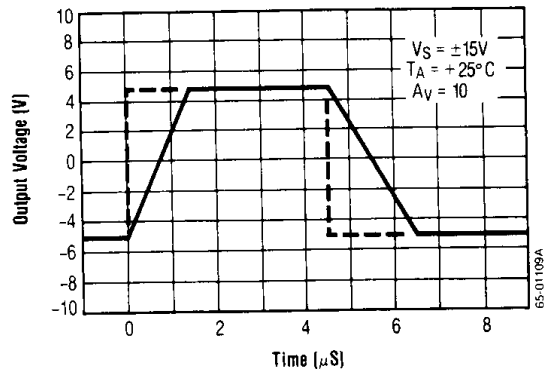
Quiescent Current as a Function of Supply Voltage



Transient Response

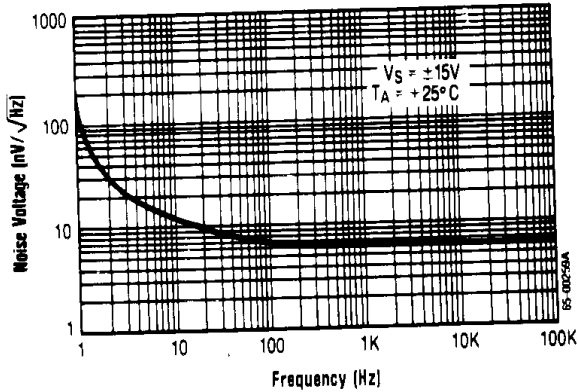


Voltage Follower Large Signal Pulse Response

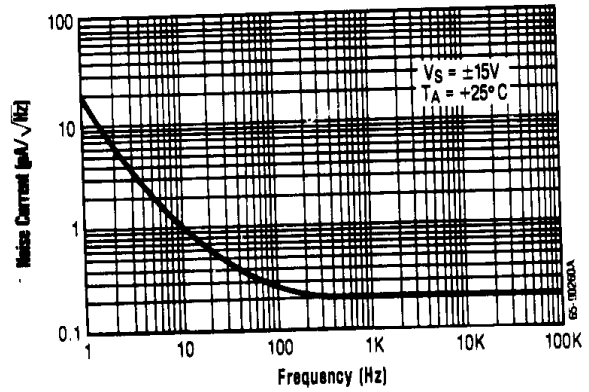


Typical Performance Characteristics (Continued)

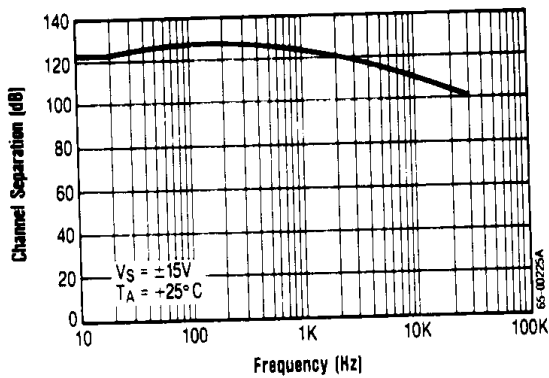
Input Noise Voltage as a Function of Frequency



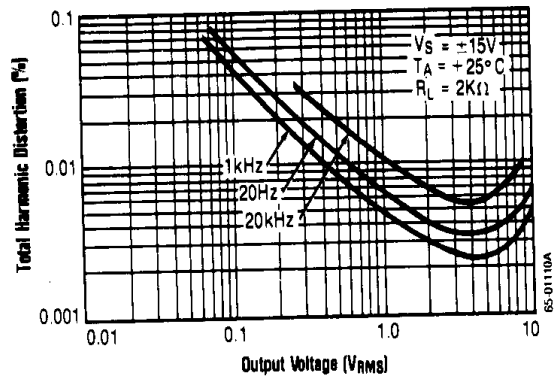
Input Noise Current as a Function of Frequency



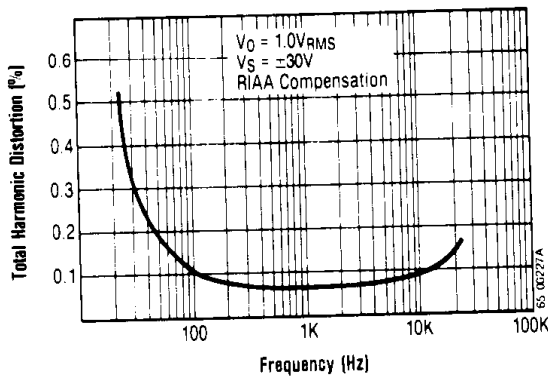
Channel Separation



Total Harmonic Distortion vs. Output Voltage



Distortion vs. Frequency



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**Comparison of Standard
vs Micro-Pak**

